NSN 5961-01-307-1642

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-307-1642 **Inclosure Material:** Metal **Overall Length:** 0.810 inches **Overall Height:** 0.810 inches **Overall Width:** 0.810 inches **Component Name And Quantity:** 7 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 660.0 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 5.00 amperes forward current, average absolute all semiconductor device diode and 100.00 amperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 81755-c4941 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli